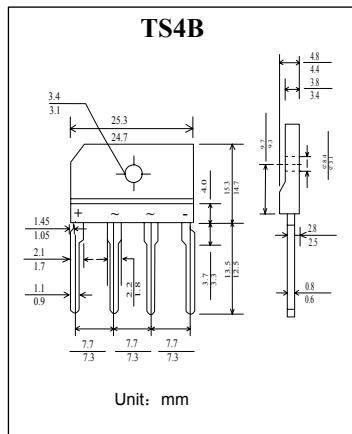




## Single-phase Silicon Bridge Rectifier

**TS4B05G**

Reverse Voltage 600 V  
Forward Current 4.0 A



### 特征 Features

- 低的反向漏电流 Low reverse leakage
- 较强的正向浪涌承受能力 High forward surge capability
- 浪涌承受能力: 120 A Surge overload rating: 120 Amperes peak

### 机械数据 Mechanical Data

- 封装: 塑料封装 Case: Molded Plastic
- 极性: 标记模压或印于本体 Polarity: Symbols molded or marked on body
- 安装位置: 任意 Mounting Position: Any

**极限值和温度特性** TA = 25°C 除非另有规定。

**Maximum Ratings & Thermal Characteristics** Ratings at 25°C ambient temperature unless otherwise specified.

	符号 Symbols	TS4B05G	单位 Unit
最大可重复峰值反向电压 Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	600	V
最大均方根电压 Maximum RMS voltage	V <sub>RMS</sub>	420	V
最大直流阻断电压 Maximum DC blocking voltage	V <sub>DC</sub>	600	V
最大正向平均整流电流 TC = 100°C Maximum average forward rectified current	I <sub>F(AV)</sub>	4.0	A
峰值正向浪涌电流 8.3ms单一正弦半波 Peak forward surge current 8.3 ms single half sine-wave	I <sub>FSM</sub>	120	A
最大反向峰值电流 @TA = 75°C Maximum peak reverse current full cycle	I <sub>R(AV)</sub>	30	μA
典型热阻 Typical thermal resistance	R <sub>θJA</sub>	5.5	°C/W
工作结温和存储温度 Operating junction and storage temperature range	T <sub>j</sub> , T <sub>TSG</sub>	-55 --- +150	°C

**电特性** TA = 25°C 除非另有规定。

**Electrical Characteristics** Ratings at 25°C ambient temperature unless otherwise specified.

	符号 Symbols	TS4B05G	单位 Unit
最大正向电压 Maximum forward voltage	I <sub>F</sub> = 4.0A	V <sub>F</sub>	1.1
最大反向电流 Maximum reverse current	TA= 25 °C TA= 125 °C	I <sub>R</sub>	5 500
典型结电容 V <sub>R</sub> = 4.0V, f = 1MHz Type junction capacitance	C <sub>j</sub>	40	pF

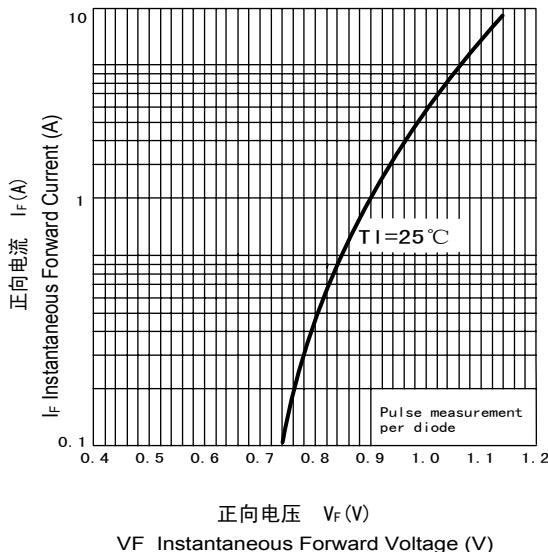
**TS4B05G**

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 Forward Current 4.0 A

## Characteristic Curves

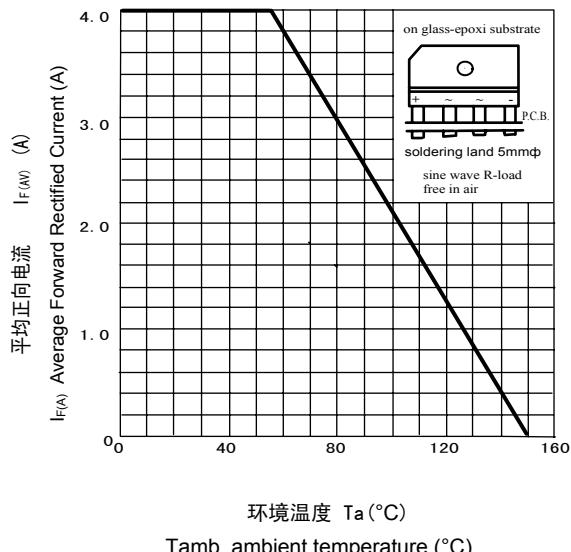
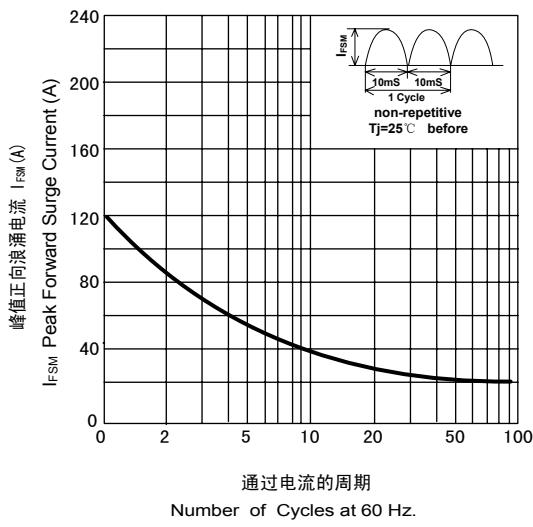
正向特性曲线 (典型值)

TYPICAL FORWARD CHARACTERISTIC



正向电流降额曲线

FORWARD CURRENT DERATING CURVE


 浪涌特性曲线 (最大值)  
 MAXIMUM NON REPETITIVE  
 PEAK FORWARD SURGE CURRENT


功率损耗曲线

FORWARD POWER DISSIPATION

